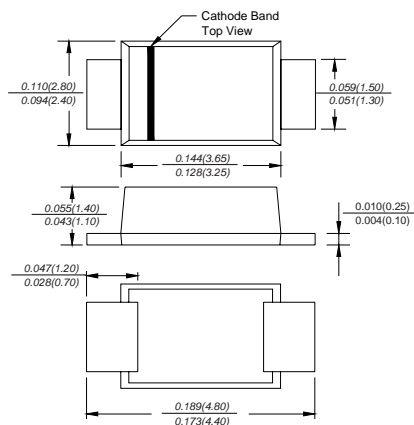


# SS12AF THRU SS120AF

## SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts Forward Current - 1.0 Ampere

### SMAF



Dimensions in inches and (millimeters)

### FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ Built-in strain relief, ideal for automated placement
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed: 260°C/10 seconds at terminals

### MECHANICAL DATA

**Case:** SMAF molded plastic body

**Terminals:** leads solderable per MIL-STD-750, Method 2026

**Polarity:** Color band denotes cathode end

**Mounting Position:** Any

**Weight:** 0.0014 ounce, 0.038 grams

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

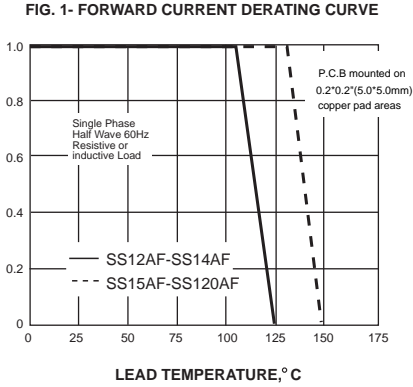
	SYMBOLS	SS12AF	SS13AF	SS14AF	SS15AF	SS16AF	SS18AF	SS110AF	SS115AF	SS120AF	UNITS
Maximum repetitive peak reverse voltage	$V_{RRM}$	20	30	40	50	60	80	100	150	200	V
Maximum RMS voltage	$V_{RMS}$	14	21	28	35	42	56	70	105	140	V
Maximum DC blocking voltage	$V_{DC}$	20	30	40	50	60	80	100	150	200	V
Maximum average forward rectified current at $T_L$ (see fig. 1)	$I_{(AV)}$	1.0									A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load	$I_{FSM}$	30.0									A
Maximum instantaneous forward voltage at 1.0A	$V_F$	0.45	0.55	0.70		0.85		0.95		V	
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	$I_R$	0.5			0.1		mA				
Typical junction capacitance (NOTE 1)	$C_J$	110			90			pF			
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	88									$^\circ\text{C}/\text{W}$
Operating junction temperature range	$T_J$	-55 to +125			-55 to +150						$^\circ\text{C}$
Storage temperature range	$T_{STG}$	-55 to +150									$^\circ\text{C}$

**Note:** 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

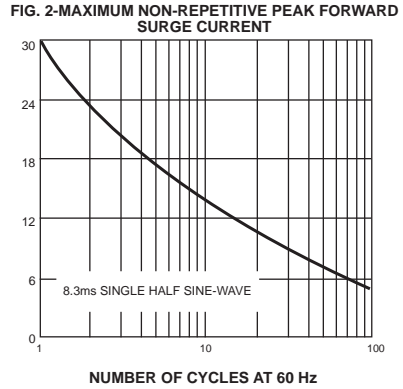
2. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

# RATINGS AND CHARACTERISTIC CURVES SS12AF THRU SS120AF

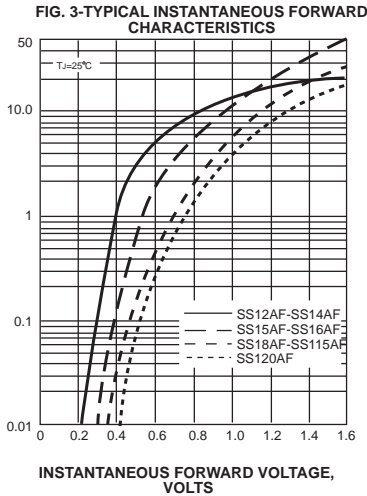
AVERAGE FORWARD RECTIFIED CURRENT, AMPERES



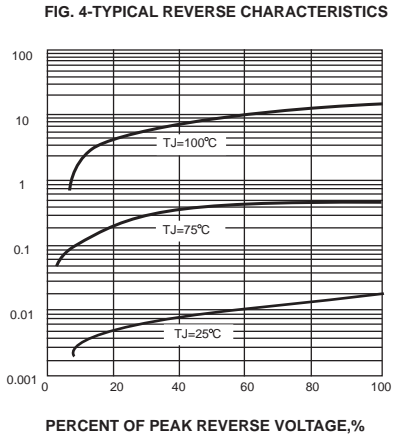
PEAK FORWARD SURGE CURRENT, AMPERES



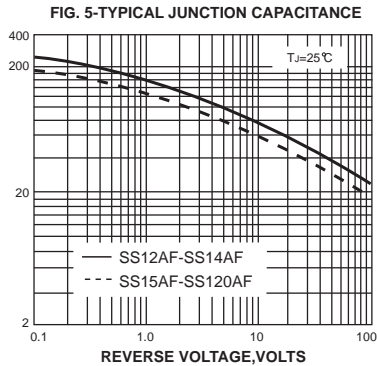
INSTANTANEOUS FORWARD CURRENT, AMPERES



INSTANTANEOUS REVERSE CURRENT, MILLIAMPERES



JUNCTION CAPACITANCE, pF



TRANSIENT THERMAL IMPEDANCE, °C/W

